

0.9V Drive Nch MOSFET

RYM002N05

Structure

Silicon N-channel MOSFET

Features

- 1) High speed switing.
- 2) Small package(VMT3).
- 3) Ultra low voltage drive(0.9V drive).

Application

Switching

Packaging specifications

	• .		
Type	Package	Taping	
	Code	T2CL	
	Basic ordering unit (pieces)	8000	
RYM002N0	0		

● Absolute maximum ratings (Ta = 25°C)

Paran	Symbol	Limits	Unit	
Drain-source voltage		V_{DSS}	50	V
Gate-source voltage		V_{GSS}	±8	V
Drain current	Continuous	I_D	±200	mA
	Pulsed	I _{DP} *1	±800	mA
Source current	Continuous	I _S	125	mA
(Body Diode)	Pulsed	I _{SP} *1	800	mA
Power dissipation		P _D *2	150	mW
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

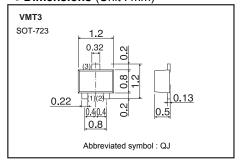
^{*1} Pw≤10µs, Duty cycle≤1%

• Thermal resistance

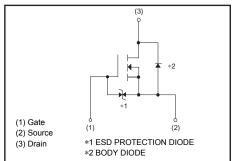
Parameter	Symbol	Limits	Unit
Channel to Ambient	Rth (ch-a)*	833	°C/W

^{*} Each terminal mounted on a recommended land.

● Dimensions (Unit : mm)



• Inner circuit



^{*2} Each terminal mounted on a recommended land.

● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	1	-	±10	μA	$V_{GS}=\pm 8V, V_{DS}=0V$
Drain-source breakdown voltage	V _{(BR)DSS}	50	-	-	٧	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	1	-	1	μA	V _{DS} =50V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	0.3	1	0.8	>	V_{DS} =10V, I_{D} =1mA
		1	1.6	2.2		I _D =200mA, V _{GS} =4.5V
Otatia dusia assuma as atata		1	1.7	2.4		I _D =200mA, V _{GS} =2.5V
Static drain-source on-state resistance	R _{DS (on)}	-	2.0	2.8	Ω	I _D =200mA, V _{GS} =1.5V
rosistanos		1	2.2	3.3		I _D =100mA, V _{GS} =1.2V
		ı	3.0	9.0		I _D =10mA, V _{GS} =0.9V
Forward transfer admittance	IY _{fs} I*	0.2	1	ı	S	I _D =200mA, V _{DS} =10V
Input capacitance	C _{iss}	-	26	-	pF	V _{DS} =10V
Output capacitance	C _{oss}	1	6	ı	рF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	1	3	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	1	5	-	ns	I _D =100mA, V _{DD} ≒25V
Rise time	t _r *	1	8	-	ns	V _{GS} =4.5V
Turn-off delay time	t _{d(off)} *	-	17	-	ns	R_L =250 Ω
Fall time	t _f *	-	43	-	ns	R_G =10 Ω

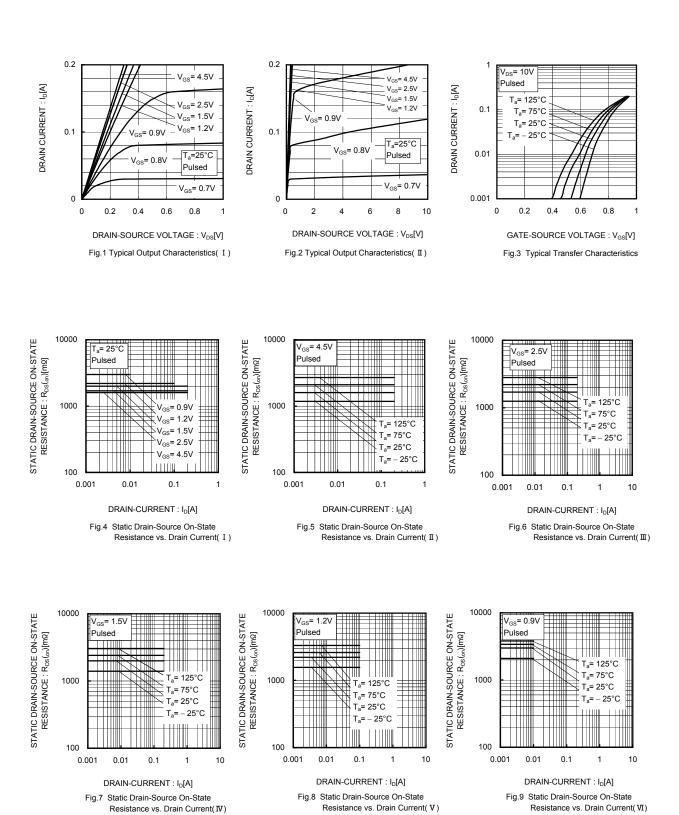
^{*}Pulsed

●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward Voltage	V _{SD} *	-	-	1.2	V	I _s =200mA, V _{GS} =0V

^{*}Pulsed

● Electrical characteristics curves (Ta = 25°C)



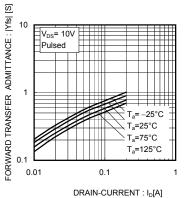


Fig.10 Forward Transfer Admittance vs. Drain Current

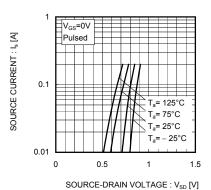


Fig.11 Reverse Drain Current vs. Sourse-Drain Voltage

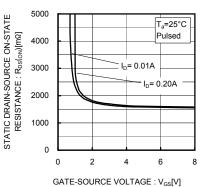


Fig.12 Static Drain-Source On-State
Resistance vs. Gate Source Voltage

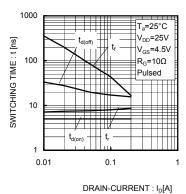


Fig.13 Switching Characteristics

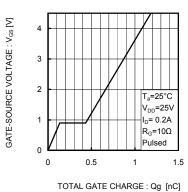


Fig.14 Typical Capacitance vs. Drain-Source Voltage

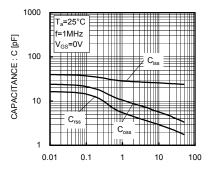


Fig.15 Typical Capacitance vs. Drain-Source Voltage

DRAIN-SOURCE VOLTAGE : $V_{DS}[V]$

Measurement circuits

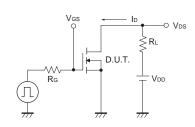


Fig.1-1 Switching time measurement circuit

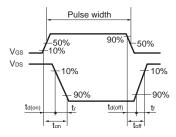


Fig.1-2 Switching waveforms

Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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